



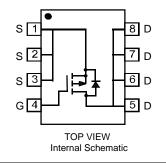
Features

- Low On-Resistance
 - 11mΩ @ V_{GS} = -10V
 - 17mΩ @ V_{GS} = -4.5V
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Lead Free By Design/RoHS Compliant (Note 2)
- "Green" Device (Note 4)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOP-8L
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals Connections: See Diagram
- Terminals: Finish Matte Tin annealed over Copper lead frame. Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.072g (approximate)





Maximum Ratings $@T_A = 25^{\circ}C$ unless otherwise specified

Chara	cteristic		Symbol	Value	Units
Drain-Source Voltage			V _{DSS}	-30	V
Gate-Source Voltage			V _{GSS}	±20	V
Drain Current (Note 1)	Steady State	T _A = 25°C T _A = 70°C	ID	-13 -9.75	A
Pulsed Drain Current (Note 3)			I _{DM}	-45	A

SOP-8L

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 1)	PD	2.5	W
Thermal Resistance, Junction to Ambient	R _{θJA}	50	°C/W
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	°C

Notes: 1. Device mounted on 2 oz. Copper pads on FR-4 PCB with $R_{\theta JA} = 50^{\circ}C/W$.

2. No purposefully added lead.

3. Pulse width ${\leq}10\mu S,$ Duty Cycle ${\leq}1\%.$

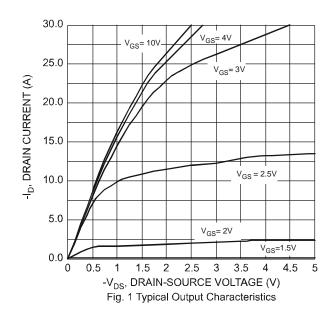
4. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.

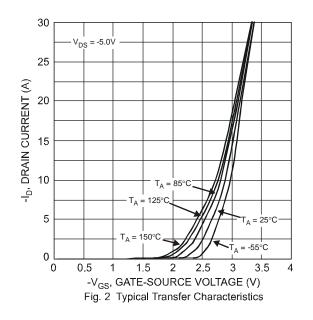


Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 5)	Symbol	IVIIII	тур	IVIAN	Unit	Test condition	
Drain-Source Breakdown Voltage	BV _{DSS}	-30	_	_	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current	IDSS	_		-1	μA	$V_{DS} = -30V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}			±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 5)	000		1				
Gate Threshold Voltage	V _{GS(th)}	-1		-2	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
Static Drain-Source On-Resistance			9	11	~0	V _{GS} = -10V, I _D = -13A	
Static Drain-Source On-Resistance	R _{DS} (ON)	_	14	17	mΩ	$V_{GS} = -4.5V, I_D = -10A$	
Forward Transconductance	g fs	_	15	_	S	$V_{DS} = -15V, I_D = -8A$	
Diode Forward Voltage (Note 5)	V _{SD}	-0.5	_	-1.1	V	$V_{GS} = 0V, I_{S} = -2.1A$	
DYNAMIC CHARACTERISTICS							
Input Capacitance	C _{iss}	_	2748		pF		
Output Capacitance	Coss	_	357		pF	V _{DS} = -20V, V _{GS} = 0V f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}	_	356	_	pF		
Gate Resistance	R _G	_	2.0	_	Ω	$V_{DS} = 0V, V_{GS} = 0V$ f = 1.0MHz	
SWITCHING CHARACTERISTICS						·	
Total Gate Charge	Qg	_	30.0 60.4	_		$V_{DS} = -10V, V_{GS} = -4.5V, I_D = -13A$ $V_{DS} = -10V, V_{GS} = -10V, I_D = -13A$	
Gate-Source Charge	Q _{qs}		7.2	_	nC	V _{DS} = -10V, V _{GS} = -10V, I _D = -13A	
Gate-Drain Charge	Q _{gd}		16.4			V _{DS} = -10V, V _{GS} = -10V, I _D = -13A	
Turn-On Delay Time	t _{d(on)}		11.2			$V_{DS} = -15V, V_{GS} = -10V,$ $I_D = -1A, R_G = 6.0\Omega$	
Rise Time	tr		12.4				
Turn-Off Delay Time	t _{d(off)}		104.9		ns		
Fall Time	t _f		61.7]		

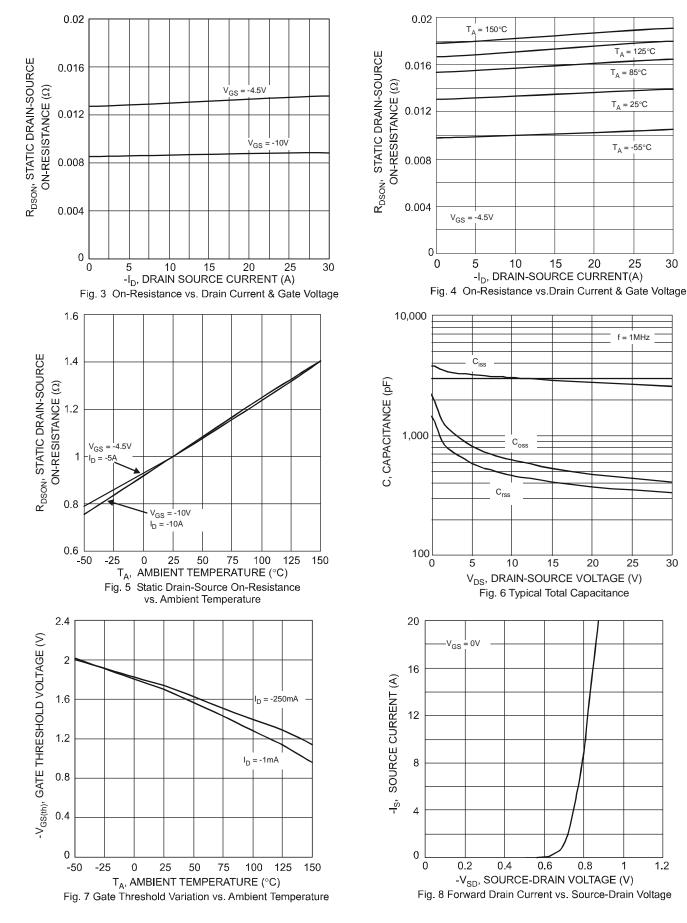
Notes: 5. Short duration pulse test used to minimize self-heating effect.



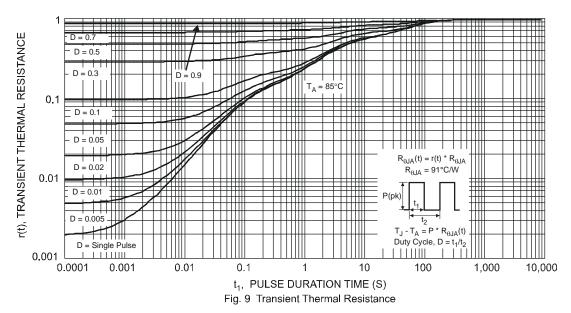




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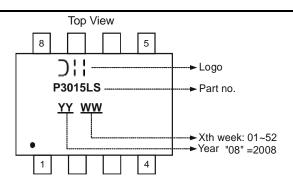




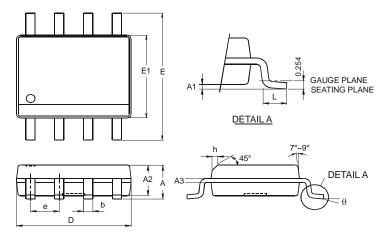
Ordering Information (Note 6)			
Part Number	Case	Packaging	
DMP3015LSS-13	SOP-8L	2500/Tape & Reel	

Notes: 6. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



Package Outline Dimensions

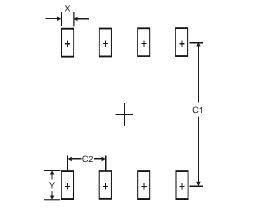


SOP-8L			
Dim	Min	Max	
Α	_	1.75	
A1	0.08	0.25	
A2	1.30	1.50	
A3	0.20 Тур.		
b	0.3	0.5	
D	4.80	5.30	
Е	5.79	6.20	
E1	3.70	4.10	
e	1.27 Typ.		
h	_	0.35	
L	0.38	1.27	
θ	0°	8°	
All Dimensions in mm			

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DMP3015LSS





Dimensions	Value (in mm)
Х	0.60
Y	1.55
C1	5.4
C2	1.27

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